M. Sc. II (Semester-IV) Examination PHYSICS

Subject – Physics Paper Title – Nuclear and Particle Physics Paper Code – MPT401

Question Bank

6Marks Question

- 1. Explain properties of nuclear force.
- 2. Explain properties of deuteron.
- 3. Solve two body deuteron problem and show that deuteron is loosely bound.
- 4. Show that differential scattering cross section is independent of scattering angle for neutron-proton scattering using partial wave analysis
- 5. Show that neutron-proton force is strongly spin dependent based on coherent scattering of slow neutrons from ortho- and para-hydrogen molecule.
- 6. Explain meson theory of exchange forces with diagram.
- 7. Give classification of radiation detectors.
- 8. Explain in short different regions of current pulse versus applied voltage curve of gaseous detectors with graph.
- 9. Describe construction and working of the ionization chamber with well labelled diagram.
- 10.Describe construction and working of the proportional chamber with well labelled diagram.
- 11.Describe construction and working of the scintillation detectors with well labelled diagram.
- 12.Describe construction and working of the semiconductor detectors with well labelled diagram.
- 13. Write note on Lithium drifted junction detector.
- 14. Write a note on the existence of magic number.
- 15. Explain single particle shell model with harmonic oscillator potential.
- 16. Explain single particle shell model with square well potential.
- 17. Explain single particle shell model with Wood Saxon potential with spin-orbit interaction.
- 18.Discuss the predictions of the shell model.
- 19. Explain spin with the help of single particle shell model.
- 20. Write a note on the nuclear magnetic moments.
- 21. Write a note on the collective model.
- 22. Discuss evidences of nuclear shell model.
- 23. Write a note on the fundamental forces.
- 24. Discuss baryon octet and decuplet in detail.
- 25. Write brief note on conservation laws in elementary particle reaction.

4Marks Question

- 1. Explain deuteron has no excited S-states.
- 2. Write note on neutron-proton scattering at low energy.
- 3. Starting from low energy scattering amplitude, show that zero energy scattering cross section is four times the maximum classical area.

- 4. Write note on shape independent effective range theory in neutron-proton scattering.
- 5. Why p-p scattering is capable of more accuracy than neutron-proton scattering?
- 6. What is similarity between neutron- neutron and proton-proton forces?
- 7. Write a short note on exchange forces.
- 8. Explain basic radiation detector system with well labelled diagram.
- 9. Describe construction and working of the Multiwire proportional chamber with well labelled diagram.
- 10.Describe construction and working of the planer drift chamber with well labelled diagram.
- 11. What are advantages and disadvantages of scintillation counters?
- 12. What are material properties of semiconductor detector?
- 13. What are advantages and disadvantages of semiconductor detectors?
- 14.Draw the sequence of the nuclear energy level according to the shell model by taking into account spin orbit interaction.
- 15.Draw a classification diagram of the elementary particles.
- 16. Write a note on the Gell-Mann-Nishijima formula.
- 17. Write a note on the quarks.
- 18.Draw the weight diagram for the meson octet.
- 19.Draw the weight diagram for the baryon octet.
- 20.Draw the weight diagram for the baryon decuplet.
- 21. Write short note on conservation law of hypercharge.
- 22. Write short note on conservation law of lepton number
- 23. Write short note on conservation law of baryon number.
- 24. Write short note on conservation law of strangeness number.
- 25. Write short note on conservation law of isospin.
- 26. Write short note on conservation law of third component of isospin.
- 27. Write a note on the leptons
- 28. Discuss in detail baryons.
- 29. Write a note on the quarks.
- 30. Write a note on the mesons.
- 31. Write a note on the hadrons.

Identify the missing particle (4 marks for each reaction)

$$32.K^{-} + P = \pi^{0} + X$$

 $33.K^{-} + P = K^{+} + X$
 $34.\pi^{-} + P = K^{0} + X$
 $35.P + P = \pi^{+} + n + \Lambda + X$

2Marks Questions

- 1. What is scattering length?
- 2. What is difference between ortho-hydrogen molecule and para-hydrogen molecule?
- 3. Give two forms of nuclear potential.
- 4. What is experimental evidence for the existence of non-central force?
- 5. What is general form of non-central force?
- 6. Which particle is exchanged between nucleons for explanation of saturation of nuclear force?
- 7. Define radiation detector.

- 8. Define ideal detector.
- 9. Enlist names of different detectors depending upon type of information produced.
- 10. What are the types of two detectors depending upon type of signal produced?
- 11.Draw basic radiation detector system.
- 12. Enlist the names of different regions of current pulse versus applied voltage curve of gaseous detectors.
- 13. In recombination region, why current pulse increases with increase applied voltage?
- 14. Which gases are filled inside ionization chamber?
- 15. Which gases are filled inside proportional chamber?
- 16. Which material is used for preparation of axial anode wire of proportional chamber?
- 17. Which factors affect size of current pulse in recombination region?
- 18. Which factors affect size of current pulse in saturation region?
- 19. Enlist the names of ionizations occurring in proportional chamber.
- 20. What is primary ionization?
- 21. What is secondary ionization?
- 22. What is Townsend avalanche?
- 23. Which material is used for preparation of photodiode in scintillation detector?
- 24. Which material is used for preparation of dynode in scintillation detector?
- 25. Which factors affect size of current pulse in scintillation detector?
- 26. What are organic scintillators?
- 27. Which are inorganic scintillators?
- 28. What is conversion efficiency and emission spectra of ZnS activated with Ag?
- 29. What is conversion efficiency and emission spectra of ZnS activated with Cu?
- 30. Enlist two limitations of inorganic scintillators.
- 31. What is conversion efficiency and emission spectra of NaI activated with Thallium?
- 32. Enlist two disadvantages of organic scintillators.
- 33. Who and when did introduce first solid-state nuclear detector AgCl crystal intrinsic semiconductor?
- 34. Enlist the types of semiconductor detector.
- 35. Enlist two reasons of using Lithium in Lithium drifted junction detector.

Name which conservation laws violated

$$36.P = \bar{p} + \gamma + \gamma 37.\Omega^{-} = P + \pi^{-} + \mu^{-} + \bar{v}_{\mu}$$

$$38.K^{-} + n = \Sigma^{+} + \pi^{0}$$
$$39.\pi^{-} + P = n + \pi^{0}$$

$$40.P = n + e^+ + v_e$$

M. Sc. II (Semester-IV) Examination PHYSICS

Thin Solid Film: Deposition and Properties (Paper Code – MPT 402) Sub Code: 92114

Question Bank

Short Note

- 1) Write down four technical applications of thin film
- 2) What is mean by epitaxial film
- 3) Explain crystallite size
- 4) What is full form of EDAx and XRD
- 5) Write down four applications of UV-Visible spectroscopy
- 6) Write types of electron gun used in SEM
- 7) Write working of objective lense in STEM
- 8) What is mean by adatom and accommodation coefficent
- 9) Explain crystallite size
- 10) What is full form of EDAX and XRD
- 11) Write down four applications of AFM
- 12) Write types of electron gun used in SEM
- 13) Define the terms crystallographic structure of thin film
- 14) What is mean by empinging surface and empinging atom
- 15) Explain the term density of thin film
- 16) What is full form of EDAX and SEM
- 17) Write down four applications of AFM
- 18) Write types of electron gun used in SEM

Short Answer

- 1) What is the influence of substrate epiaxial growth of thin film.
 - 2) Explain theories of epitaxy.
 - 3) Explain the term condensation process.
 - 4) Explain the concept influence of deposition parameters on crystalite site.
 - 5) Write short note on epitaxial growth of film
 - 6) Explain lattice constant of thin film.
- 7)Describe Flash evaporation method
- 8) What is spray pyrolysis techniques of thin film deposition
- 9) What is electron beam evaporation
- 10) Give application of plasma-enhanced CVD.
- 11)Write short note on Laser evaporation
- 12) Discuss indirect method of heating in PVD method
- 13) What are process variables in CVD?
- 14) Discuss electrodeposition of Cds thin films
- 15) State and explain electron beam evaporation for obtaining high purity films.
- 16) Discuss merits of MOCVD method.
- 17) Explain the stresses in thin films.

- 18) Explain adhesion in the films.
- 19) Discuss the conductivity of discontinuous metal films.
- 20) Write note on fundamental optical properties of thin films.
- 21) What is the merits of ellipsometry method in thin films?
- 22) Explain Mechanical properties of thin film
- 23) Explain electrical conduction in thin film
- 24) Explain electrical and magnetic properties of thin films.
- 25) Discuss application of semiconducting thin films.
- 26) Write short note on electrical conduction in thin
- 27) Write short note on AFM.
- 28) Write short note on EDAX.
- 29) What is Radio frequency Sputtering
- 30) Write down difference between Chemical and Physical methods
- 31) Write a note on Surface roughness of thin film
- 32) Write in brief x-ray diffraction spectroscopy
- 33) Explain the stresses in thin films.
- 34) Explain Mechanical properties of thin film
- 35) Write short note on density of thin film.
- 36) Explain the term liquid like coalescence
- 37) Write In brief x-ray diffraction spectroscopy
- 38) What is Electron Beam Evaporation
- 49) Write a note on weight difference method and Stylus method

Long Answer

- 1) Discuss different stages involved in thin film formation. Explain the role of substrate in nucleation process.
- 2) Explain growth process of thin film formation and describe liquid like coalescence.
- 3) Describe the influence of deposition parameters on properties of thin film. Explain the term crystallite
- 4) What is epitaxial growth phenomenon. Explain theories of epitaxy
- 5) Explain in detail triode sputtering for thin film deposition
- 6) Discuss dependence of sputtering yield on sputtering varients. Explain with suitable diagram the working of low pressure sputtering method
- 7) Discuss PVD and CVD methods of thin film deposition. Compare merits and demerits of physical vapor deposition and chemical vapor deposition methods.
- 8) What are the merits of chemical bath deposition method.discuss deposition of compound thin film by chemical bath deposition method.
- 9) With the help of neat digram, explain glow discharge sputtering process what is reactive sputtering?
- 10) Explain Cathod sputtering. Discuss factors affecting glow discharge.
- 11) Explain process variables in CVD method. Explain preparation of a si by photo-CVD method.
- 12) Explain ellipsometry technique for determination of optical conastants. Explain Dow-Redfield model of Optical absorption of optical constant measurements in thin films.
- 13) derive an expression for conductivity of continuous metal films.

- 14) Discuss Reflection and Interferometric methods of optical constant measurements in thin films.
- 15) Explain construction and working of Scanning Electron Microscope. Write down its applicatios
- 16) Explain mechanism of thin film formation: condensation and nucleation
- 17) With the help of neat diagram, explain glow discharge sputtering process.
- 18) Explain principle, construction and working of atomic force microscopy
- 19) Explain different Types of Chemical methods.
- 20) Describe various steps involved in growth process of thin film formation.
- 21) With the help of neat digram, explain glow discharge sputtering process.
- 22) Explain mechanism of thin film formation: condensation and nucleation
- 23) Write principle, construction and working of X-ray photo electron . spectroscopy
- 24) Explain principle, construction and working of SEM
- 25) Explain growth process of thin film formation and describe liquid like coalescence.
- 27) What are the merits of chemical bath deposition method.discuss deposition of compound thin film by chemical bath deposition method.

M. Sc. II (Semester-IV) Examination_____ PHYSICS Subject – Physics

M. Sc. II Physics Solid State Physics - IV (MPT 403)

Short note (2Mark)

- 1. What is Fill Factor in Solar Cell?
- 2. What is Short circuit current?
- 3. Write a short note on Tandem solar cells.
- 4. Explain shunt resistance in solar cell.
- 5. Write the uses of solar cells.
- 6. Write a note on open circuit voltage?
- 7. Explain band gap energy.
- 8. Explain photo-voltaic effect.
- 9. What is super-capacitor?
- 10. Define efficiency of solar cell.
- 11. Write a note on Series resistance in solar cell?
- 12.Photoelectric Effect
- 13.P-N Junction
- 14. Dye sensitized solar cells (DSSCs).
- 15. Hydrogen energy
- 16. Lithium batteries
- 17.Ni/Cd batteries
- 18.Lead-acid batteries
- 19. Photoelectrochemical (PEC) solar cells
- 20. Battery life cycle

Long answer questions.

- 1. Write note on effect of parasitic resistances and temperature on efficiency of the solar cell.
- 2. Describe Steam methane reforming (SMR) process of Hydrogen production in detail
- 3. What are different types of Supercapacitors? Explain it in detail
- 4. Explain solar cell parameters. (Shunt resistance, Fill factor & Efficiency)
- 5. With neat labelled diagram explain Dye sensitized solar cells (DSSCs).
- 6. Explain applications of Hydrogen energy.
- 7. Write a short note on Primary and Secondary batteries.
- 8. Explain Lithium batteries and Ni/Cd batteries.

- 9. Explain briefly basics of electrochemical cell.
- 10. What is upper limit of short circuit current, open circuit voltage and fill factor for a single junction solar cell?
- 11. How Hydrogen can be stored? Explain it in detail.
- 12. What is IQE analysis? How can an IQE analysis be used to probe the different parts of solar cells?

Short answer questions.

- 1. What are requirements for high short circuit current in solar cell?
- 2. Write a short note on Quantum dot sensitized solar cells.
- 3. What are the similarities and differences between supercapacitors and batteries?
- 4. Explain the Physical methods of Hydrogen storage.
- 5. Describe the Hydrogen safety processes in detail.
- 6. Write a short note on Photoelectrochemical (PEC) solar cells
- 7. Describe construction and working of Hydrogen fuel cell.
- 8. Write a short note on Regon plot.
- 9. What are the design criteria for obtaining higher open circuit voltage of a cell?
- 10. Write the applications of batteries.
- 11. Explain briefly Lead-acid batteries.
- 12. Write a short note on Photoelectrochemical water splitting.
- 13. Write a short note on Polymer solar cells.
- 14. Describe the Hydrogen safety processes in detail.
- 15. Explain the term Battery voltage and Battery life cycle.
- 16.Explain the effect of band gap energy of semiconductor material on efficiency of solar cell.

What are the design criteria for obtaining higher open circuit voltage o

M. Sc. II (Semester-IV) Examination PHYSICS

Subject – Physics Paper Code: MPT 404 A Paper Title: Electronic Devices Question Bank

Q.1) Short Note

- 1) Define Photonic devices with examples
- 2) Write down full form of MOSFET.
- 3) Define the term heterojunction LASER
- 4) What is role of SiO₂ layer in MOSFET?
- 5) What is meant by Input devices explain with example.
- 6) What do you mean by "forward blocking state" in SCR?
- 7) What is CCD?
- 8) Draw simplified symbol of n-channel and p-channel MOSFET.
- 9) What is bit and byte?
- 10) Write down full form and definition of LED?
- 11) Define photonic devices with one example.
- 12) Define the terms Static and dynamic memory.
- 13) Draw circuit symbol of SCR.
- 14) What do you mean by LASER explain with definition and full form.
- 15) Give types of MOSFET.
- 16) Define LED and LASER
- 17) What do you mean by transition state in case of SCR?
- 18) Define the terms Static and dynamic memory.
- 19) Give any two characteristic of MOSFET.
- 20) Give any two advantages of SCR.
- 21) Give any two applications of DIAC.
- 22) Give any two advantages of TRIAC.
- 23) Give any two applications of SCR.
- 24) Give any two applications of TRIAC.
- 25) Give any two disadvantages of TRIAC.
- 26) Give any two disadvantages of SCR.
- 27) Give any two disadvantages of DIAC.
- 28) What are output devices?
- 29) Write down examples of Static and dynamic memry
- 30) .what is photonic devices?

Q.2) Long answer questions.

- 1) Describe characteristics of n-channel Enhancement type MOSFET
- 2) Explain Types of semiconductor memory in detail.
- 3) What is primary and secondary storage devices? Explain with examples.
- 4) Compare SCR and TRIC.
- 5) Explain construction and working of n-channel enhancement type MOSFET.
- 6) Explain construction and working of LED with neat diagram
- 7) Explain Construction and working of DIAC.
- 8) Explain Construction and working of SCR.
- 9) Explain Types of semiconductor memory in detail.
- 10) Explain construction and working of p-channel MOSFET.
- 11) Explain steps involve in working of LASER Action
- 12) Draw and explain output and input characteristics for transistor common emit configuration.
- 13) Explain types of semiconductor memory in details.
- 14) Compare between CB,CE,CC amplifiers.
- 15) Explain BJT as a switch.
- 16) Draw construction and drain characteristics of JFET.Explain its operation
- 17) Explain SCR as a switch and important features of SCR.
- 18) Give draw back, advantages and applications of SCR.
- 19) Give draw back, advantages and applications of DIAC.
- 20) Give draw back, advantages and applications of TRIAC.
- 21) State different types of transistor configuration and compare between them.
- 22) What is DC load line? Derive expression force amplifier.
- 23) Explain frequency response I case of transistor.
- Write down the difference between Rom and RAM
- 25) Explain difference between Laser and LED
- 26) Explain the process of expanding memory size.
- 27) Explain visible and organic LED
- 28) Describe read and write operation in detail
- 29) Write down construction working of Solid state LASER
- 30) Describe classification and characteristics of memories.

Q.5) Short answer questions

- 1) Write a note on memory organization and operation.
- 2) Draw and explain input and output characteristics for transistor common base (CB) configuration.
- 3) Write a note on Cache memory.
- 4) Explain read and write operation in memory device.
- 5) Draw and explain static characteristics of SCR.
- 6) How one can achieve expand memory size of the device?
- 7) Write down basic comparison of static and dynamic memory
- 8) Compare Diac and Triac.
- 9) What is primary and secondary memory?
- 10) Write a note on memory organization and operation
- 11) Give advantages of SCR.
- 12) Write a note on "transistor biasing in the active region".

- 13) Give advantages of MOSFET over JFET.
- 14) Write a note on Cache memory.
- 15) Explain effect of silicon dioxide layer on input resistance and capacitance.
- 16) Write down basic comparison of static and dynamic memory.
- 17) Give applications of SCR.
- 18) What is primary and secondary memory?
- 19) Write a note on memory organization and operation
- 20) Explain population inversion in details.
- 21) Write a note on "transistor biasing in the active region".
- 22) Give advantages of MOSFET over JFET.
- 23) Write a note on Cache memory.
- 24) Explain effect of silicon dioxide layer on input resistance and capacitance.
- 25) Write down basic comparison of static and dynamic memory.
- 26) Give applications of LASER.
- 27) What is primary and secondary memory?
- 28) For BJT as a switch, why CB and CC configuration are not preferred, explain.
- 29) Explain pinch of voltage and Gate of voltage.
- 30)Draw and explain input characteristics of CE configuration.
- 31) Give draw back and advantages of TRIAC.
- 32)Compare between CB and CC configuration.
- 33) Compare between CB and CE configuration.
- 34) Write a note on memory organization
- 35) What is the Charge couple memory Devices?
- 36) Explain the types of semiconducting Lasers
- 37) Explain Radioactive transition and
- 38) Write a short note on optical absorption.
- 39) Explain characteristics of memories.
- 40) Write a note on organic LED with examples
